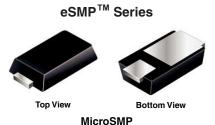


## Vishay General Semiconductor

# **Surface Mount Schottky Barrier Rectifiers**



PRIMARY CHARACTERISTICS				
I <sub>F(AV)</sub>	1.0 A			
$V_{RRM}$	30 V, 40 V			
I <sub>FSM</sub>	25 A			
V <sub>F</sub> at I <sub>F</sub> = 1.0 A	0.41 V			
T <sub>J</sub> max.	150 °C			

#### **TYPICAL APPLICATIONS**

For use in low voltage high frequency inverters, freewheeling, dc-to-dc converters, and polarity protection applications.

### **FEATURES**

• Very low profile - typical height of 0.68 mm



• Ideal for automated placement



Low forward voltage drop, low power losses

ROHS COMPLIANT HALOGEN

FREE

High efficiency

 Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C

 Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC

· Halogen-free

### **MECHANICAL DATA**

Case: MicroSMP

Molding compound meets UL 94V-0 flammability

rating.

Base P/N-E3 - RoHS compliant, commercial grade
Base P/N-M3 - halogen-free and RoHS compliant,

commercial grade

Terminals: Matte tin plated leads, solderable per

J-STD-002 and JESD22-B102

E3 and M3 suffix meets JESD 201 class 1A whisker

test

Polarity: Color band denotes the cathode end

<b>MAXIMUM RATINGS</b> (T <sub>A</sub> = 25 °C unless otherwise noted)					
PARAMETER	SYMBOL	MSS1P3	MSS1P4	UNIT	
Device marking code		13	14		
Maximum repetitive peak reverse voltage	V <sub>RRM</sub>	30	V		
Maximum average forward rectified current (Fig. 1)	I <sub>F(AV)</sub>	1.0		Α	
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	I <sub>FSM</sub>	25		А	
Operating junction and storage temperature range	T <sub>J</sub> , T <sub>STG</sub>	- 55 to + 150		°C	

## MSS1P3 & MSS1P4

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<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>A</sub> = 25 °C unless otherwise noted)						
PARAMETER	TEST C	ONDITIONS	SYMBOL	TYP.	MAX.	UNIT
Maximum instantaneous forward voltage <sup>(1)</sup>	I <sub>F</sub> = 0.5 A I <sub>F</sub> = 1.0 A	T <sub>J</sub> = 25 °C	V <sub>F</sub>	0.41 0.48	- 0.55	· V
	I <sub>F</sub> = 0.5 A I <sub>F</sub> = 1.0 A	T <sub>J</sub> = 125 °C		0.32 0.41	- 0.46	
Maximum reverse current (2)	rated V <sub>R</sub>	T <sub>J</sub> = 25 °C T <sub>J</sub> = 125 °C	I <sub>R</sub>	8.5 4.5	200 15	μA mA
Typical junction capacitance	4.0 V, 1 MHz		CJ	50	-	pF

#### Notes:

(1) Pulse test: 300 µs pulse width, 1 % duty cycle

(2) Pulse test: Pulse width ≤ 40 ms

THERMAL CHARACTERISTICS (T <sub>A</sub> = 25 °C unless otherwise noted)					
PARAMETER	SYMBOL	MSS1P3	MSS1P4	UNIT	
Typical thermal resistance <sup>(1)</sup>	$egin{array}{c} R_{ hetaJA} \ R_{ hetaJL} \ R_{ hetaJC} \end{array}$	125 30 40		°C/W	

#### Note:

(1) Thermal resistance from junction to ambient and junction to lead mounted on P.C.B. with 6.0 x 6.0 mm copper pad areas  $R_{\theta JL}$  is measured at the terminal of cathode band.  $R_{\theta JC}$  is measured at the top center of the body

ORDERING INFORMATION (Example)						
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
MSS1P4-E3/89A	0.006	89A	4500	7" diameter plastic tape and reel		
MSS1P4-M3/89A	0.006	89A	4500	7" diameter plastic tape and reel		

### **RATINGS AND CHARACTERISTICS CURVES**

(T<sub>A</sub> = 25 °C unless otherwise noted)

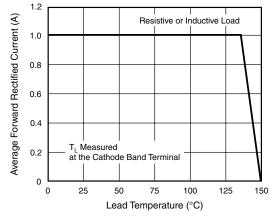


Figure 1. Maximum Forward Current Derating Curve

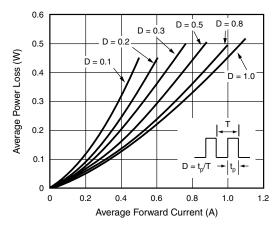


Figure 2. Forward Power Loss Characteristics



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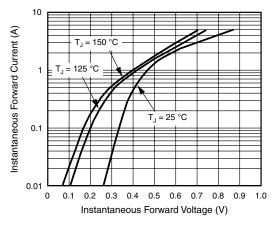


Figure 3. Typical Instantaneous Forward Characteristics

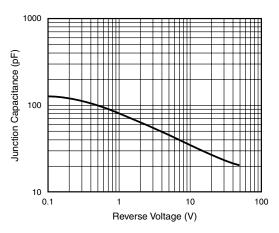


Figure 5. Typical Junction Capacitance

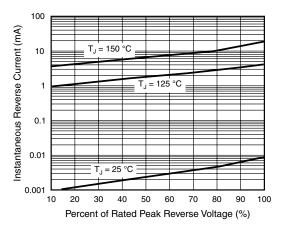


Figure 4. Typical Reverse Characteristics

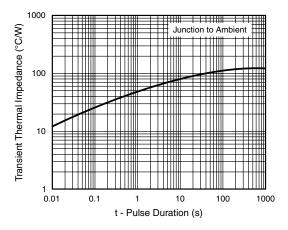


Figure 6. Typical Transient Thermal Impedance

(0.50)

### **PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)

#### MicroSMP 0.059 (1.50) 0.030 (0.75) Cathode Band 0.043 (1.10) 0.022 (0.55) 0.055 (1.40) 0.047 (1.20) 0.030 (0.75) 0.039 (0.98) 0.031 (0.78) 0.022 (0.55) 0.091 (2.30) 0.083 (2.10) 0.106 (2.70) 0.091 (2.30) **Mounting Pad Layout** 0.079 0.032 (2.00)(0.80) 0.029 (0.73) 0.032 0.043 0.025 (0.63) (1.10) (0.80) ŧ. 0.011 (0.27) 0.005 (0.12) 0.020



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